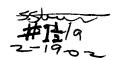
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



In re the Application of:

Havemann et al.

Examiner: TBD

Serial No:

TBD

Art Unit:

TBD

Filed:

11/01/01

Docket No.: TI-27506

For:

INTEGRATED CIRCUIT HAVING A DOPED POROUS DIELECTRIC AND

METHOD OF MANUFACTURING THE SAME

PRELIMINARY AMENDMENT

November 1, 2001

Assistant Commissioner for Patents

Washington, DC 20231

Dear Sir:

Please amend the above referenced application as follows:

In the Specification:

Page 1, before line 1, insert -This application claims priority under 35 USC §

9,

The state of the s

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119(e)(1) of provisional application numbers 60/251,494 filed 12/05/00.--